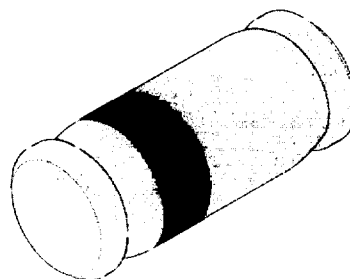


Silicon Epitaxial Planar Z Diodes

Features

- Very sharp reverse characteristic
- Low reverse current level
- Available with tighter tolerances
- Very high stability
- Low noise



94 9171

Applications

Voltage stabilization

Absolute Maximum Ratings

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Value	Unit
Power dissipation	$R_{thJA} \leq 300\text{K/W}$		P_V	500	mW
Z-current			I_Z	P_V/V_Z	mA
Junction temperature			T_j	175	$^\circ\text{C}$
Storage temperature range			T_{stg}	-65...+175	$^\circ\text{C}$

Maximum Thermal Resistance

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Symbol	Value	Unit
Junction lead		R_{thJL}	300	K/W
Junction ambient	on PC board 50mmx50mmx1.6mm	R_{thJA}	500	K/W

Characteristics

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Forward voltage	$I_F = 200\text{mA}$		V_F			1.5	V

Type TZMC...	V _{Znorm} V	I _{ZT} for mA	V _{ZT} ¹⁾ and V	r _{zT} Ω	r _{zjk} at I _{ZK} Ω	I _R and I _R ²⁾ at V _R μA	μA	V	TK _{VZ} %/K	
2V4	2.4	5	2.28 to 2.56	< 85	< 600	1	< 100	< 50	1	-0.09 to -0.06
2V7	2.7	5	2.5 to 2.9	< 85	< 600	1	< 10	< 50	1	-0.09 to -0.06
3V0	3.0	5	2.8 to 3.2	< 90	< 600	1	< 4	< 40	1	-0.08 to -0.05
3V3	3.3	5	3.1 to 3.5	< 90	< 600	1	< 2	< 40	1	-0.08 to -0.05
3V6	3.6	5	3.4 to 3.8	< 90	< 600	1	< 2	< 40	1	-0.08 to -0.05
3V9	3.9	5	3.7 to 4.1	< 90	< 600	1	< 2	< 40	1	-0.08 to -0.05
4V3	4.3	5	4.0 to 4.6	< 90	< 600	1	< 1	< 20	1	-0.06 to -0.03
4V7	4.7	5	4.4 to 5.0	< 80	< 600	1	< 0.5	< 10	1	-0.05 to +0.02
5V1	5.1	5	4.8 to 5.4	< 60	< 550	1	< 0.1	< 2	1	-0.02 to +0.02
5V6	5.6	5	5.2 to 6.0	< 40	< 450	1	< 0.1	< 2	1	-0.05 to +0.05
6V2	6.2	5	5.8 to 6.6	< 10	< 200	1	< 0.1	< 2	2	0.03 to 0.06
6V8	6.8	5	6.4 to 7.2	< 8	< 150	1	< 0.1	< 2	3	0.03 to 0.07
7V5	7.5	5	7.0 to 7.9	< 7	< 50	1	< 0.1	< 2	5	0.03 to 0.07
8V2	8.2	5	7.7 to 8.7	< 7	< 50	1	< 0.1	< 2	6.2	0.03 to 0.08
9V1	9.1	5	8.5 to 9.6	< 10	< 50	1	< 0.1	< 2	6.8	0.03 to 0.09
10	10	5	9.4 to 10.6	< 15	< 70	1	< 0.1	< 2	7.5	0.03 to 0.1
11	11	5	10.4 to 11.6	< 20	< 70	1	< 0.1	< 2	8.2	0.03 to 0.11
12	12	5	11.4 to 12.7	< 20	< 90	1	< 0.1	< 2	9.1	0.03 to 0.11
13	13	5	12.4 to 14.1	< 26	< 110	1	< 0.1	< 2	10	0.03 to 0.11
15	15	5	13.8 to 15.6	< 30	< 110	1	< 0.1	< 2	11	0.03 to 0.11
16	16	5	15.3 to 17.1	< 40	< 170	1	< 0.1	< 2	12	0.03 to 0.11
18	18	5	16.8 to 19.1	< 50	< 170	1	< 0.1	< 2	13	0.03 to 0.11
20	20	5	18.8 to 21.2	< 55	< 220	1	< 0.1	< 2	15	0.03 to 0.11
22	22	5	20.8 to 23.3	< 55	< 220	1	< 0.1	< 2	16	0.04 to 0.12
24	24	5	22.8 to 25.6	< 80	< 220	1	< 0.1	< 2	18	0.04 to 0.12
27	27	5	25.1 to 28.9	< 80	< 220	1	< 0.1	< 2	20	0.04 to 0.12
30	30	5	28 to 32	< 80	< 220	1	< 0.1	< 2	22	0.04 to 0.12
33	33	5	31 to 35	< 80	< 220	1	< 0.1	< 2	24	0.04 to 0.12
36	36	5	34 to 38	< 80	< 220	1	< 0.1	< 2	27	0.04 to 0.12
39	39	2.5	37 to 41	< 90	< 500	1	< 0.1	< 5	30	0.04 to 0.12
43	43	2.5	40 to 46	< 90	< 600	0.5	< 0.1	< 5	33	0.04 to 0.12
47	47	2.5	44 to 50	< 110	< 700	0.5	< 0.1	< 5	36	0.04 to 0.12
51	51	2.5	48 to 54	< 125	< 700	0.5	< 0.1	< 10	39	0.04 to 0.12
56	56	2.5	52 to 60	< 135	< 1000	0.5	< 0.1	< 10	43	0.04 to 0.12
62	62	2.5	58 to 66	< 150	< 1000	0.5	< 0.1	< 10	47	0.04 to 0.12
68	68	2.5	64 to 72	< 200	< 1000	0.5	< 0.1	< 10	51	0.04 to 0.12
75	75	2.5	70 to 79	< 250	< 1500	0.5	< 0.1	< 10	56	0.04 to 0.12

¹⁾ Tighter tolerances available on request.

²⁾ at T_j = 150°C

Typical Characteristics ($T_j = 25^\circ\text{C}$ unless otherwise specified)

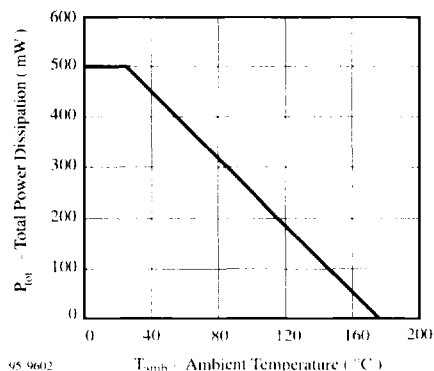


Figure 1 : Total Power Dissipation vs. Ambient Temperature

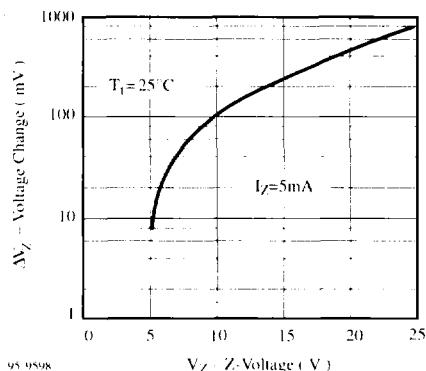
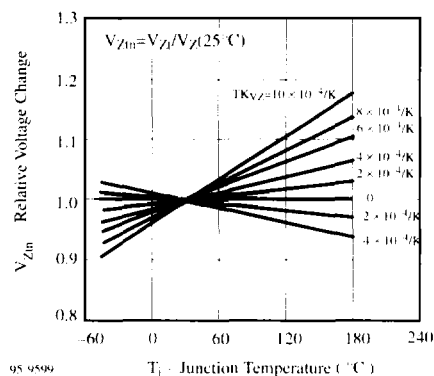
Figure 2 : Typical Change of Working Voltage under Operating Conditions at $T_{\text{amb}} = 25^\circ\text{C}$ 

Figure 3 : Typical Change of Working Voltage vs. Junction Temperature

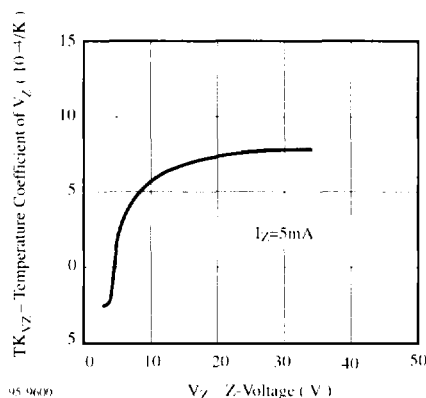
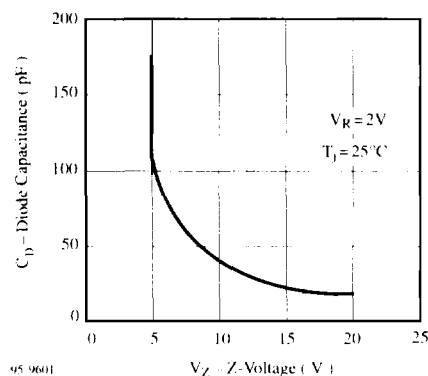
Figure 4 : Temperature Coefficient of V_Z vs. Z-Voltage

Figure 5 : Diode Capacitance vs. Z-Voltage

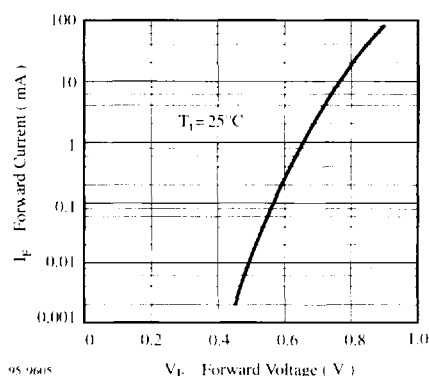


Figure 6 : Forward Current vs. Forward Voltage

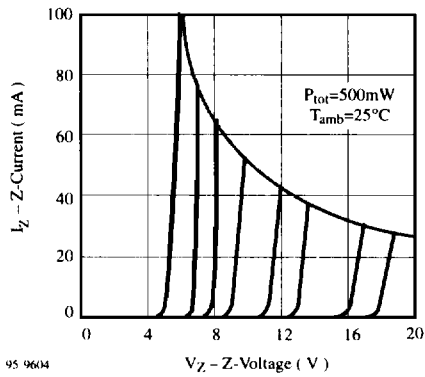


Figure 7 : Z-Current vs. Z-Voltage

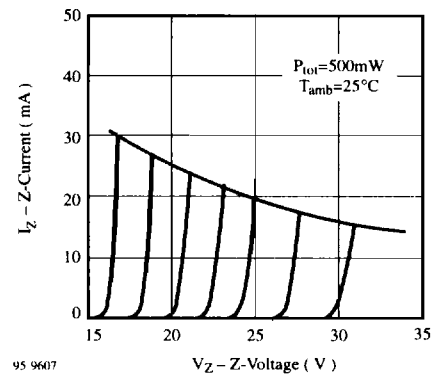


Figure 8 : Z-Current vs. Z-Voltage

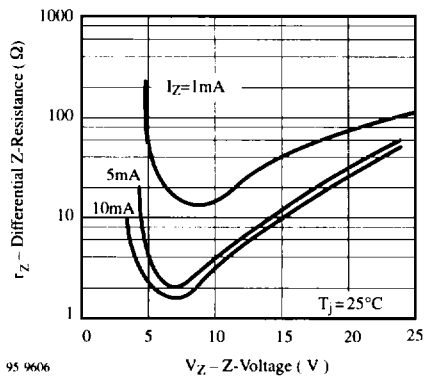


Figure 9 : Differential Z-Resistance vs. Z-Voltage

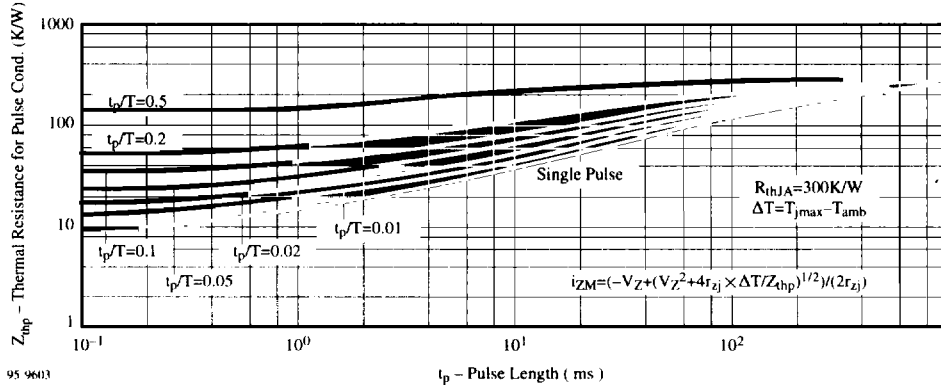


Figure 10 : Thermal Response

Dimensions in mm

